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WT-160-2024

FACULTY OF SCIENCE

M.Sc. (First Year) (First Semester) EXAMINATION

NOVEMBER/DECEMBER, 2024

(CBCS/New Pattern)

PHYSICS

Paper PHY-104

(Electronic Devices and Applications)

(Saturday, 14-12-2024)

Time—Three Hours

Time: 10.00 a.m. to 1.00 p.m.

Maximum Marks—75

Note :— (i) *All* questions are compulsory.

- (ii) Figures to the right indicate full marks.
- What is MOSFET? What are the types of MOSFET? Explain the construction and working of *n*-channel E-MOSFET.

Or

- What is extrinsic semiconductor? Why does current flow in the forward bias and there is no current in the reverse bias condition?
- (b) What is bipolar transistor? Explain working of PNP transistor in FR bias.

P.T.O.

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2	Expla	in in detail the co	onstruction	n, workin	g principle a	and I-V char	acteristics			
	of sola	ar cell.		Or			15			
	(a) What is Phototransistor ? Explain the operation and V-I characteristics									
		of phototransistor	r. 411				8			
	(b) Explain the construction, working of photodiode and give its									
		applications.					7			
3.	Descri	be the function of	f an op-a	mp as ar	adder and	subtractor.	15			
				Or						
	(a) Explain operation with the help of diagram for first order high pass									
		filter using Op-	Amp.				8			
	(b) Explain in ideal characteristics of Op-Amp.									
4.	What are sychronous and asynchronous counters? Explain MOD-6									
	async	hronous counter.					15			
				Or						
	(a) Define flip-flops. Draw neat circuit diagram and explain the truth table									
		for S-R flip-flop.					8			
	(b) What is encoder and decoder? Explain the working of BCD to decimal									
		decoder.					7			

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- 5. Write short notes on any three out of four:
 - (a) Principle of operation of UJT
 - (b) LED (Light Emitting Diode)
 - (c) Op-Amp as an differentiator
 - (d) Basic gates.

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